

Study of an hybrid mangetometer: YIG

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Study of an hybrid magnetometer: YIG



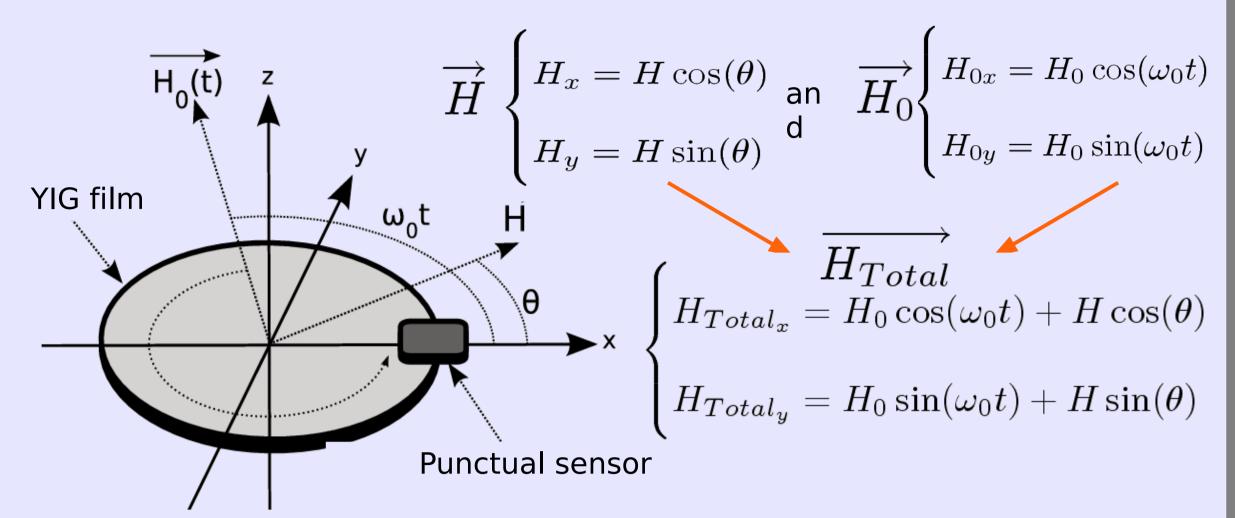
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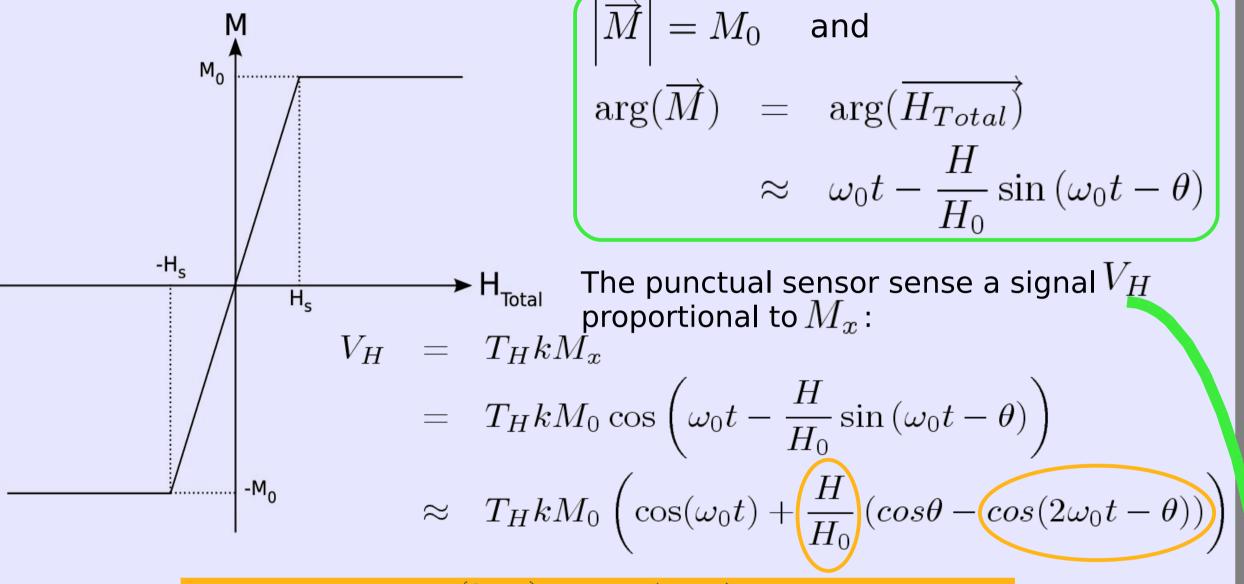
The work presented here deals with the study of a flux-gate type magnetometer which use a rotating magnetization. This principle allows to sense the different space components of the magnetic field and to reduce the noise due to Barkhausen jumps. The device was setted-up at the laboratory of physical metallurgy of the national technological university of Athens.

First of all, studying physical properties of the used material allows to deduce his crystalline structure, to evaluate his behavior under a rotating magnetic excitation and to validate the choice of this material. Then, a theoretical approach of the rotating excitation principle allows to understand the interest of this kind of device and to see which elements are changing performances on sensibility or magnetic noise. This theoretical approach finally leads to expose and to analyze the practical realization of using this working principle as developed by the Greek laboratory. It allows to understand encountered difficulties and to evaluate the effect on performances due to compromises needed. Finally, some experimental results are exposed, validating the working principle and leading to think about the possibility of evolution of this device.

Working principle:



If $\left|\overrightarrow{H_{Total}}\right| \geq \left|\overrightarrow{H_s}\right|$ the magnetization \overrightarrow{M} of the material is saturated so :

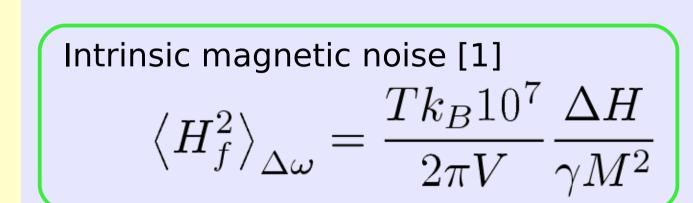


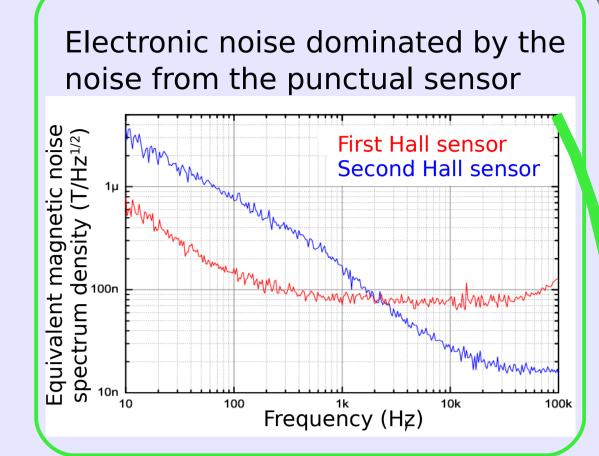
Demodulation by $\cos(2\omega_0 t)$ and $\sin(2\omega_0 t)$ allows us to deduce

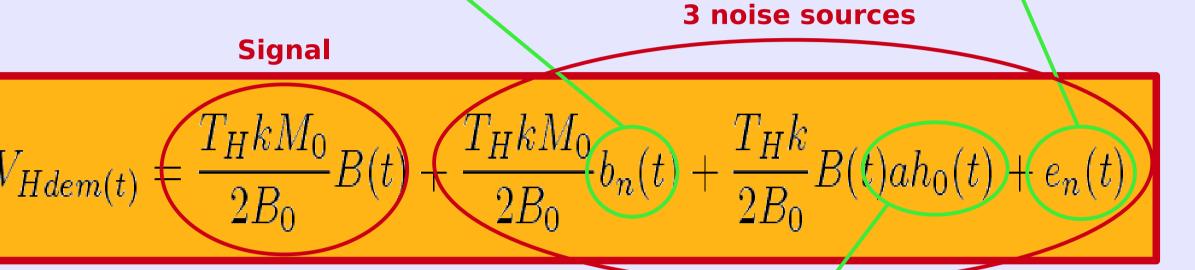
both H and heta with a single magnetometer.

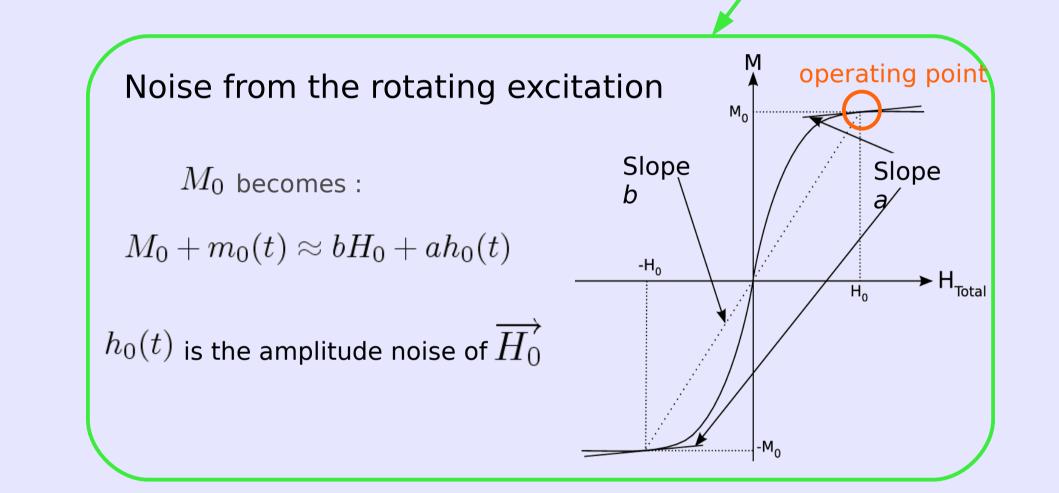
SENSITIVITY:
$$T_r = -\frac{k M_0}{2 \mu_0 H_0} T_H = -\frac{k M_0}{2 B_0} T_H$$

Noise sources:





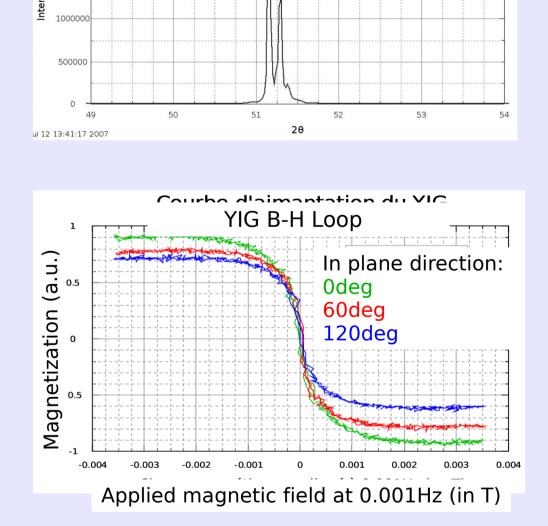


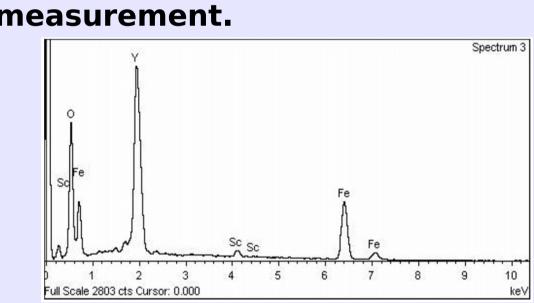


Materials:

YiG - Y₃Fe₂(FeO₄)₃ - Cubique

YIG: SEM, EDS, XRD and B-H Loop measurement.





Yttrium Iron Garnet
Single-crystal
YScFeO -> YIG
Solid solution of Sc
Miller level: 640 (in plane) and 444
Strong susceptibility
In-plane anisotropic behavior of the B-H Loop

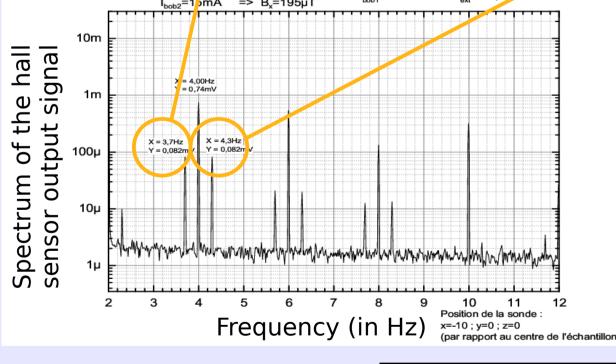
Results: We apply an

We apply an external magnetic field: $\overrightarrow{H}egin{array}{l} H_x=H\cos(\omega t) \\ = H_y=0 \end{array}$ with $H\ll H_0$

So the sensed output signal becomes:

$$V_{H} = -T_{H}kM_{0}\frac{H}{2H_{0}}\cos(\omega t)\cos(2\omega_{0}t) \qquad \qquad \text{Amplitude Modulation}$$

$$= -T_{H}kM_{0}\frac{H}{4H_{0}}\cos((2\omega_{0}+\omega)t) - T_{H}kM_{0}\frac{H}{4H_{0}}\cos((2\omega_{0}-\omega)t)$$
Champ tournant à 2Hz:
$$\begin{bmatrix} Champ \text{ tournant à 2Hz} : \\ Dobi = 15 \text{ BM } \Rightarrow B_{0}=30 \text{ put} \\ Dobi = 2,8\text{ BM } \Rightarrow B_{0}=3.9 \text{ put} \end{bmatrix}$$
Champ a mesurer à 0,3Hz:
$$\begin{bmatrix} Champ \text{ tournant à 2Hz} : \\ Dobi = 2,8\text{ BM } \Rightarrow B_{0}=3.9 \text{ put} \end{bmatrix}$$



The sensitivity T_r could be evaluated from the amplitude of both AM spectral components.

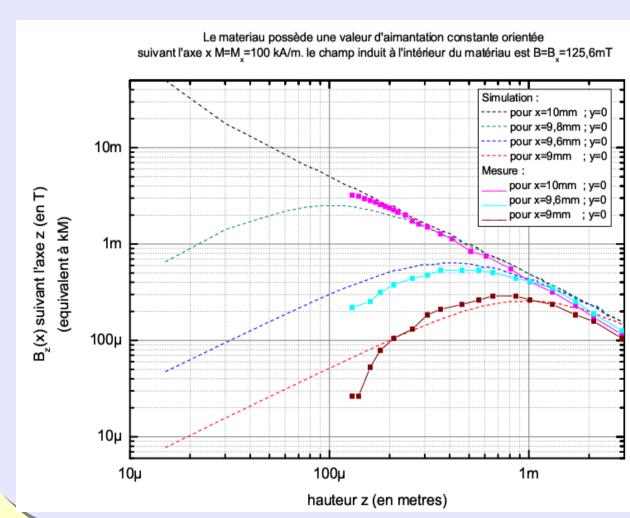
	Excitation field	kM_0	Sensitivity	Noise power spectrum	Example for
	amplitude B_0		T_r	density in T/\sqrt{Hz}	f = 10 Hz
	Bare Hall sensor		25V/T	$\frac{8.10^{-6}}{f} + 80.10^{-9}$	$880 nT \sqrt{Hz}$
first	1 mT	$850 \mu T$	11 V/T	180.10^{-9}	$180 nT \sqrt{Hz}$
Hall				at $f_0 \geq 500 Hz$	
sensor	$180 \mu T^*$	$500 \mu T$	35 V/T	60.10-9	$60 nT \sqrt{Hz}$
				at $f_0 \geq 500 kHz$	
Second	Bare Hall sensor		2V/T	$\frac{8.10^{-6}}{\sqrt{f}} + 16.10^{-9}$	$2,5\mu T\sqrt{Hz}$
Hall sensor	1mT	2 mT	2V/T	16.10^{-9}	$16 nT \sqrt{Hz}$
used for				at $f_0 \ge 40 kHz$	
increasing	$180 \mu T^*$	not	6 V/T	$5,3.10^{-9}$	$5,3 nT \sqrt{Hz}$
k		measured		at $f_0 \ge 40 kHz$	
	Hall sensor Second Hall sensor used for increasing	$\begin{array}{c c} & \text{amplitude } B_0 \\ \hline & \text{Bare Hall sensor} \\ \hline & 1mT \\ \hline & \text{Hall} \\ \text{sensor} & 180\mu T^* \\ \hline \\ & \text{Second} & \text{Bare Hall sensor} \\ \hline & \text{Hall sensor} \\ \hline & \text{used for} \\ \hline & \text{increasing} & 180\mu T^* \\ \hline \end{array}$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$

* Not sufficient in order to saturate the material

Implementation:

<u>Punctual magnetometer</u> -> Hall effect sensor, sensing the vertical component of the field induced by the magnetization of the YIG.

k: coupling factor between YIG magnetization M and sensed field.



Optimal position of the Hall sensor in order to increase k:

as near as possible from the YIG film surface.

just on the boundary of the YIG disc

increase the space resolution of the sensor in use.

Actuals main problems:

- Noise spectrum density is dominated by the hall sensor noise.
- Low values of the coupling factor k.

Possibilities of evolution:

- Increase the coupling factor k: *optimization of the hall sensor position.
- Increase the ration M_0/B_0 : *Changing the form factor of the material *New soft magnetic material